

SQJ180EP 80 V Automotive MOSFET

3 mΩ in PowerPAK[®] SO-8L With Secure-Mounting Gull-Wing Leads

42 % LOWER R_{DS(on)} THAN THE **PRIOR GEN 80 V, N-CHANNEL DEVICE IN SIMILAR FOOTPRINT** WITH SECURE-MOUNTING **GULL-WING LEADS**





BETTER BOARD-LEVEL RELIABILITY AND MORE POWER DENSITY

- Gull-wing leads improve resilience for mechanical stress and TCE mismatch
- Rugged, reliable, and reduces up to 80 % PCB real estate for MOSFET from D²PAK
- Passed all these BLR tests:





BETTER SWITCHING EFFICIENCY FOR AUTOMOTIVE

- Optimized R_{DS} x Q_n FOM reduces loss from gate driving and increases efficiency
- 27 % improvement over prior generation SQJA78EP

Typical $R_{DS} \times Q_{\alpha}$ FOM (m $\Omega \times nC$) at 10 V

Competitor LFPAK				373	
Prior	Prior Generation		268		
				-	
SQJ180EP		195			
0	100	2	00	300	400

FOR 48 V, 24 V, AND 12 V **AUTOMOTIVE APPLICATIONS**



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